

CMOS LOGIC IC ELM7SU04B Unbuffer Inverter

<https://www.elm-tech.com>

■General description

ELM7SU04B is CMOS unbuffer inverter IC. It realizes high speed operation similar to LS-TTL with lower power consumption by CMOS features.

■Features

- Same electrical characteristic as 74HC series (output current is around 1/2 of 74HC series)
- Low consumption current : $I_{dd}=1.0\mu A$ (Max.)(Top=25°C)
- Wide power voltage range : 2.0V to 6.0V
- High speed : $T_{pd}=5ns$ (Typ.)(Vdd=5.0V)
- Symmetrical output impedance : $|I_{oh}|=I_{ol}=2mA$ (Min.)(Vdd=4.5V)
- Small package : SOT-25

■Application

- Cell phones
- Digital cameras
- Portable electrical appliances like PDA, etc.
- Computers and peripherals
- Digital electrical appliances like LCD TV sets, DVD recorders/players, STB, etc.
- Modification inside print board, adjustment of timing, solution to noise

■Selection guide

ELM7SU04BEL

Symbol	Function	U04: Unbuffer Inverter
a	Product version	B
c	Taping direction	EL: Refer to PKG file

ELM7S U04 B EL
↑ ↑ ↑
a b c

■Maximum absolute ratings

Parameter	Symbol	Limit	Unit
Power supply voltage	Vdd	-0.5 to +7.0	V
Input voltage	Vin	-0.5 to Vdd+0.5	V
Output voltage	Vout	-0.5 to Vdd+0.5	V
Input protection diode current	Iik	± 20	mA
Output parasitic diode current	Iok	± 20	mA
Output current	Iout	± 25	mA
VDD/GND current	Idd, Ignd	± 25	mA
Power dissipation	Pd	200	mW
Storage temperature	Tstg	-65 to +150	°C

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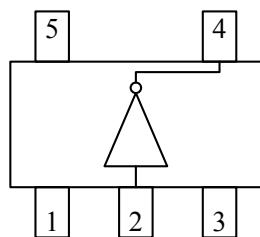
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■Suggested operating condition

Parameter	Symbol	Limit		Unit
Power voltage	Vdd	2.0 to 6.0		V
Input voltage	Vin	0 to Vdd		V
Output voltage	Vout	0 to Vdd		V
Operating temperature	Top	-40 to +85		°C
High-input down-time	tr, tf	Vdd=2.0V	0 to 1000	ns
		Vdd=4.5V	0 to 500	
		Vdd=6.0V	0 to 400	

■Pin configuration

SOT-25(TOP VIEW)



Pin No.	Pin name
1	NC
2	INY
3	GND
4	OUTX
5	VDD

Input	Output
INY	OUTX
Low	High
High	Low

■AC electrical characteristics

CL=15pF, tr=tf=6ns, Vdd=5V

Parameter	Sym.	Vdd	Top=25°C			Unit	Condition
			Min.	Typ.	Max.		
Output transition time	tTLH		4	10		ns	Refer to test circuit
	tTHL		3	10			
Propagation delay-time	tPLH		5	15		ns	Refer to test circuit
	tPHL		5	15			

CL=50pF, tr=tf=6ns

Parameter	Sym.	Vdd	Top=25°C			Top=-40 to +85°C		Unit	Condition	
			Min.	Typ.	Max.	Min.	Max.			
Output transition time	tTLH	2.0		29	125		155	ns	Refer to test circuit	
		4.5		11	25		31			
		6.0		11	21		26			
	tTHL	2.0		26	125		155	ns		
		4.5		9	25		31			
		6.0		8	21		26			
Propagation delay-time	tPLH	2.0		18	100		125	ns	Refer to test circuit	
		4.5		8	20		25			
		6.0		7	17		21			
	tPHL	2.0		17	100		125	ns		
		4.5		7	20		25			
		6.0		6	17		21			
Input capacity	Cin			5	10		10	pF		
Equivalent inner capacity	Cpd			10				pF		

* Cpd is IC's inner equivalent capacity which is calculated from non-loaded operating current consumption referred to test circuit. Averaged operating current consumption at non load is calculated as following formula: $Idd(\text{opr}) = Cpd \cdot Vdd \cdot f_{in} + Idd$

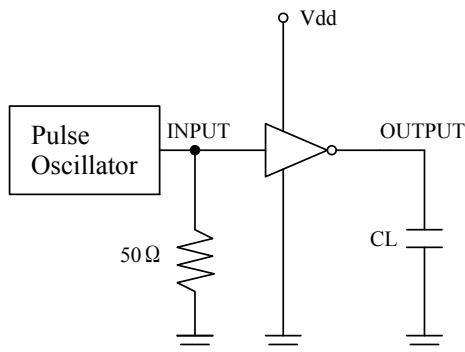
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■DC electrical characteristics

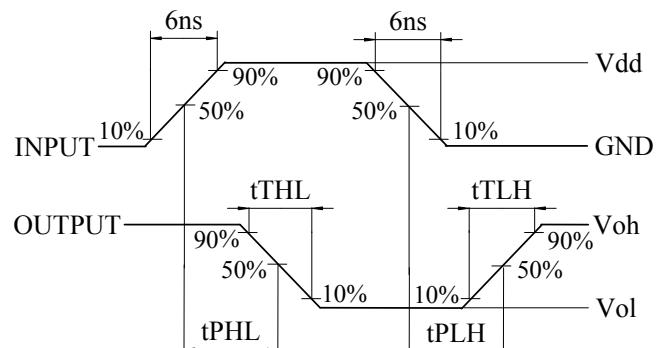
Parameter	Sym.	Vdd	Top=25°C			Top=-40 to +85°C		Unit	Condition
			Min.	Typ.	Max.	Min.	Max.		
Input voltage	Vih	2.0	1.70			1.70		V	
		4.5	3.60			3.60			
		6.0	4.80			4.80			
	Vil	2.0			0.30		0.30	V	
		4.5			0.90		0.90		
		6.0			1.20		1.20		
Output voltage	Voh	2.0	1.80	2.00		1.80		V	Vin=Vil
		4.5	4.00	4.50		4.00			
		6.0	5.50	6.00		5.50			
		4.5	4.18	4.31		4.13			Ioh=-2mA
		6.0	5.68	5.80		5.63			Ioh=-2.6mA
	Vol	2.0		0.00	0.20		0.20	V	Vin=Vih
		4.5		0.00	0.50		0.20		
		6.0		0.00	0.50		0.50		
		4.5		0.17	0.26		0.33		Iol=2mA
		6.0		0.18	0.26		0.33		Iol=2.6mA
Input current	Iin	6.0	-0.1		0.1	-1.0	1.0	μA	Vin=Vdd or GND
Static current	Idd	6.0			1.0		10.0	μA	Vin=Vdd or GND

■Test circuit



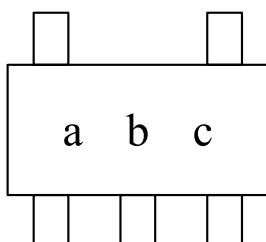
* Output should be opened when measuring current consumption.

■Measured wave pattern



■Marking

SOT-25



No.	Mark	Content
a	E	ELM7S series
b	6	ELM7SU04B
c	A to Z (except I, O, X)	Lot No.